



Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at
www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

September 2018

FOD050L, FOD053L

3.3 V and 5 V High Speed Transistor Optocouplers

Features

- Low Power Consumption
- High Speed
- Available in Single-channel 8-pin SOIC (FOD050L) or Dual-channel 8-pin SOIC (FOD053L)
- Superior CMR – $CM_H = 50\text{ kV}/\mu\text{s}$ (typical) and $CM_L = 35\text{ kV}/\mu\text{s}$ (typical)
- Guaranteed performance over temperature: 0°C to 70°C
- Safety and Regulatory Approvals:
 - UL1577, 2,500 VAC_{RMS} for 1 Minute
 - DIN-EN/IEC60747-5-5, 565 V Peak Working Insulation Voltage

Applications

- Line Receivers
- Pulse Transformer Replacement
- High-speed Logic Ground Isolation: LVTTTL/LVCMOS
- Wide Bandwidth Analog Coupling

Description

The FOD050L and FOD053L optocouplers consist of an AlGaAs LED optically coupled to a high speed photo-detector transistor. These devices are specified for operation at 3.3 V and 5 V supply voltages.

A separate connection for the bias of the photodiode improves the speed by several orders of magnitude over conventional phototransistor optocouplers by reducing the base-collector capacitance of the input transistor.

An internal noise shield provides superior common mode rejection of $CM_H = 50\text{ kV}/\mu\text{s}$ (typical) and $CM_L = 35\text{ kV}/\mu\text{s}$ (typical).

Schematics

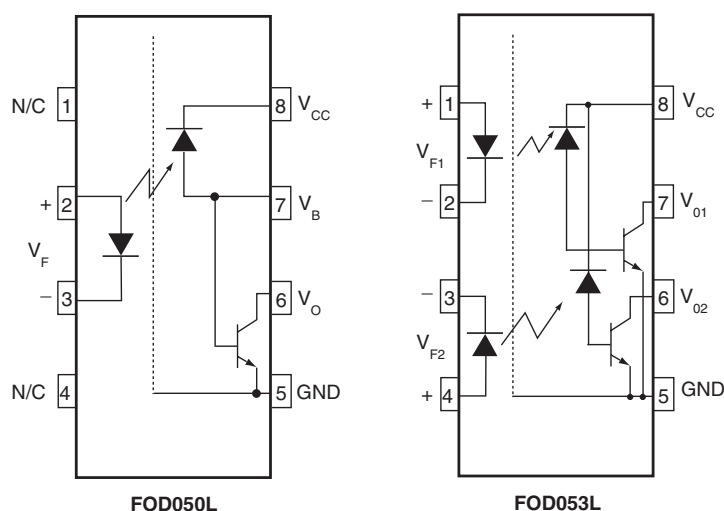


Figure 1. Schematics

Package Outline

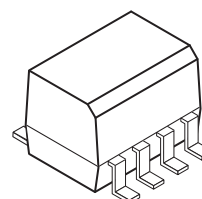


Figure 2. Package Outline

Truth Table

LED	V _O
On	LOW
Off	HIGH

Safety and Insulation Ratings

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for “safe electrical insulation” only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Parameter		Characteristics
Installation Classifications per DIN VDE 0110/1.89 Table 1, For Rated Mains Voltage	< 150 V _{RMS}	I–IV
	< 300 V _{RMS}	I–III
Climatic Classification		55/100/21
Pollution Degree (DIN VDE 0110/1.89)		2
Comparative Tracking Index		175

Symbol	Parameter	Value	Unit
V _{PR}	Input-to-Output Test Voltage, Method A, V _{IORM} × 1.6 = V _{PR} , Type and Sample Test with t _m = 10 s, Partial Discharge < 5 pC	904	V _{peak}
	Input-to-Output Test Voltage, Method B, V _{IORM} × 1.875 = V _{PR} , 100% Production Test with t _m = 1 s, Partial Discharge < 5 pC	1060	V _{peak}
V _{IORM}	Maximum Working Insulation Voltage	565	V _{peak}
V _{IOTM}	Highest Allowable Over-Voltage	4000	V _{peak}
	External Creepage	≥ 4	mm
	External Clearance	≥ 4	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥ 0.4	mm
T _S	Case Temperature ⁽¹⁾	150	°C
I _{S,INPUT}	Input Current ⁽¹⁾	200	mA
P _{S,OUTPUT}	Output Power ⁽¹⁾	300	mW
R _{IO}	Insulation Resistance at T _S , V _{IO} = 500 V ⁽¹⁾	> 10 ⁹	Ω

Note:

1. Safety limit values – maximum values allowed in the event of a failure.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter		Value	Unit
T _{STG}	Storage Temperature		-40 to +125	°C
T _{OPR}	Operating Temperature		-40 to +85	°C
T _J	Junction Temperature		-40 to +125	°C
T _{SOL}	Lead Solder Temperature		260 for 10 seconds	°C
EMITTER				
I _F (avg)	DC/Average Forward Input Current	Each Channel	25	mA
I _F (pk)	Peak Forward Input Current (50% duty cycle, 1 ms P.W.)	Each Channel	50	mA
I _F (trans)	Peak Transient Input Current (≤1 μs P.W., 300 pps)	Each Channel	1.0	A
V _R	Reverse Input Voltage	Each Channel	5	V
P _D	Input Power Dissipation (No derating required up to 85°C)	Each Channel	45	mW
DETECTOR				
I _O (avg)	Average Output Current	Each Channel	8	mA
I _O (pk)	Peak Output Current	Each Channel	16	mA
V _{EBR}	Emitter-Base Reverse Voltage	FOD050L only	5	V
V _{CC}	Supply Voltage		-0.5 to 7	V
V _O	Output Voltage		-0.5 to 7	V
I _B	Base Current	FOD050L only	5	mA
P _D	Output Power Dissipation (No derating required up to 85°C)	Each Channel	100	mW

Electrical Characteristics

$T_A = 0$ to 70°C unless otherwise specified.

Individual Component Characteristics

Symbol	Parameter	Test Conditions	Device	Min.	Typ.	Max.	Unit
EMITTER							
V_F	Input Forward Voltage	$I_F = 16\text{ mA}$, $T_A = 25^\circ\text{C}$	All		1.45	1.7	V
		$I_F = 16\text{ mA}$				1.8	
B_{VR}	Input Reverse Breakdown Voltage	$I_R = 10\text{ }\mu\text{A}$	All	5.0			V
DETECTOR							
I_{OH}	Logic High Output Current	$I_F = 0\text{ mA}$, $V_O = V_{CC} = 3.3\text{ V}$ & 5 V , $T_A = 25^\circ\text{C}$	All		0.001	1	μA
I_{CCL}	Logic Low Supply Current	$I_F = 16\text{ mA}$, $V_O = \text{Open}$, $V_{CC} = 3.3\text{ V}$ & 5 V	FOD050L			200	μA
		$I_{F1} = I_{F2} = 16\text{ mA}$, $V_O = \text{Open}$, $V_{CC} = 3.3\text{ V}$ & 5 V	FOD053L			400	
I_{CCH}	Logic High Supply Current	$I_F = 0\text{ mA}$, $V_O = \text{Open}$, $V_{CC} = 3.3\text{ V}$ & 5 V , $T_A = 25^\circ\text{C}$	FOD050L			0.3	μA
		$I_F = 0\text{ mA}$, $V_O = \text{Open}$, $V_{CC} = 3.3\text{ V}$ & 5 V	FOD053L			10	

Transfer Characteristics

Symbol	Parameter	Test Conditions	Device	Min.	Typ.	Max.	Unit
COUPLED							
CTR	Current Transfer Ratio ⁽²⁾	$I_F = 16\text{ mA}$, $V_O = 0.4\text{ V}$, $V_{CC} = 3.3\text{ V}$ & 5 V , $T_A = 25^\circ\text{C}$	All	15		50	%
V_{OL}	Logic Low Output Voltage Output Voltage	$I_F = 16\text{ mA}$, $I_O = 3\text{ mA}$, $V_{CC} = 3.3\text{ V}$ & 5 V , $T_A = 25^\circ\text{C}$	All			0.3	V

Note:

2. Current Transfer Ratio is defined as a ratio of output collector current, I_O , to the forward LED input current, I_F , times 100%.

Electrical Characteristics (Continued) $T_A = 0$ to 70°C unless otherwise specified.**Switching Characteristics** ($V_{CC} = 3.3\text{ V}$ & 5 V)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
T_{PHL}	Propagation Delay Time to Logic LOW	$R_L = 1.9\text{ k}\Omega$, $I_F = 16\text{ mA}^{(3)}$ (Figure 11)	25°C		1.0	μs
					2.0	
T_{PLH}	Propagation Delay Time to Logic HIGH	$R_L = 1.9\text{ k}\Omega$, $I_F = 16\text{ mA}^{(3)}$ (Figure 11)	25°C		1.0	μs
					2.0	
ICM_{HI}	Common Mode Transient Immunity at Logic HIGH	$I_F = 0\text{ mA}$, $V_{CM} = 1,000\text{ V}_{P-P}$, $R_L = 4.1\text{ k}\Omega$, $T_A = 25^\circ\text{C}^{(4)(5)}$ (Figure 12)	5,000	50,000		$\text{V}/\mu\text{s}$
		$I_F = 0\text{ mA}$, $V_{CM} = 1,000\text{ V}_{P-P}$, $T_A = 25^\circ\text{C}$, $R_L = 1.9\text{ k}\Omega^{(3)(5)}$ (Figure 12)	5,000	50,000		$\text{V}/\mu\text{s}$
ICM_{LI}	Common Mode Transient Immunity at Logic LOW	$I_F = 16\text{ mA}$, $V_{CM} = 1,000\text{ V}_{P-P}$, $R_L = 4.1\text{ k}\Omega$, $T_A = 25^\circ\text{C}^{(4)(5)}$ (Figure 12)	5,000	35,000		$\text{V}/\mu\text{s}$
		$I_F = 16\text{ mA}$, $V_{CM} = 1,000\text{ V}_{P-P}$, $R_L = 1.9\text{ k}\Omega^{(3)(5)}$ (Figure 12)	5,000	35,000		$\text{V}/\mu\text{s}$

Isolation Characteristics

Symbol	Characteristics	Test Conditions	Min.	Typ.	Max.	Unit
I_{I-O}	Input-Output Insulation Leakage Current	Relative humidity = 45%, $T_A = 25^\circ\text{C}$, $t = 5\text{ s}$, $V_{I-O} = 3000\text{ VDC}^{(6)}$			1.0	μA
V_{ISO}	Withstand Insulation Test Voltage	$f = 60\text{ Hz}$, $T_A = 25^\circ\text{C}$, $t = 60\text{ s}^{(6)}$	2500			V_{RMS}
R_{I-O}	Resistance (Input to Output)	$V_{I-O} = 500\text{ VDC}^{(6)}$	10^{11}	10^{12}		Ω
C_{I-O}	Capacitance (Input to Output)	$f = 1\text{ MHz}^{(6)}$		0.2		pF

Notes:

- The $1.9\text{ k}\Omega$ load represents 1 TTL unit load of 1.6 mA and $5.6\text{ k}\Omega$ pull-up resistor.
- The $4.1\text{ k}\Omega$ load represents 1 LSTTL unit load of 0.36 mA and $6.1\text{ k}\Omega$ pull-up resistor.
- Common mode transient immunity in logic high level is the maximum tolerable (positive) dV_{CM}/dt on the leading edge of the common mode pulse signal V_{CM} , to assure that the output will remain in a logic high state (i.e., $V_O > 2.0\text{ V}$). Common mode transient immunity in logic low level is the maximum tolerable (negative) dV_{CM}/dt on the trailing edge of the common mode pulse signal, V_{CM} , to assure that the output will remain in a logic low state (i.e., $V_O < 0.8\text{ V}$).
- Device is considered a two terminal device: pins 1, 2, 3 and 4 are shorted together and pins 5, 6, 7 and 8 are shorted together.

Typical Performance Curves

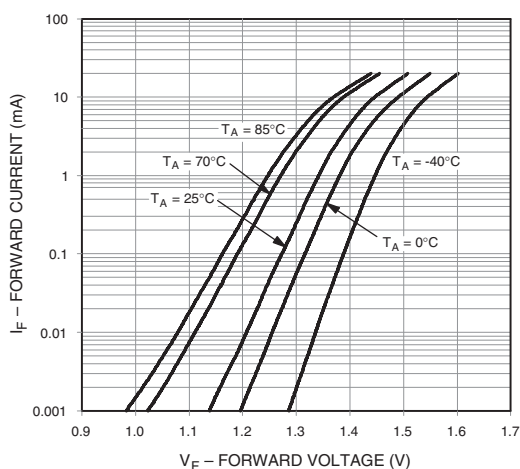


Figure 3. LED Forward Current vs. Forward Voltage

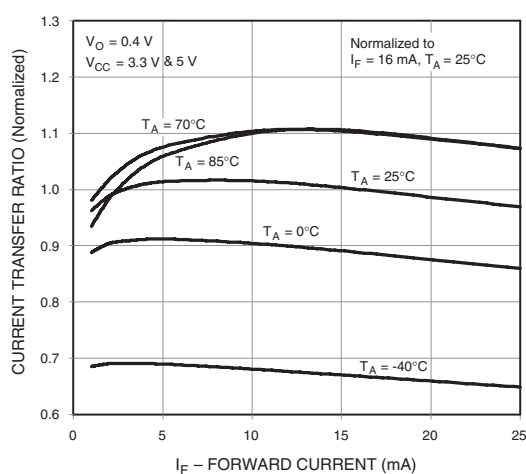


Figure 4. Current Transfer Ratio vs. Forward Current

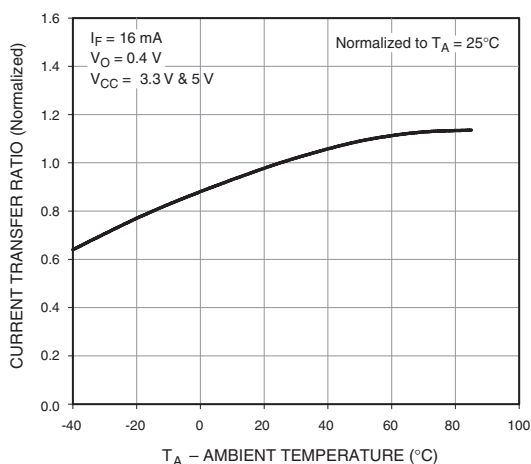


Figure 5. Current Transfer Ratio vs. Ambient Temperature

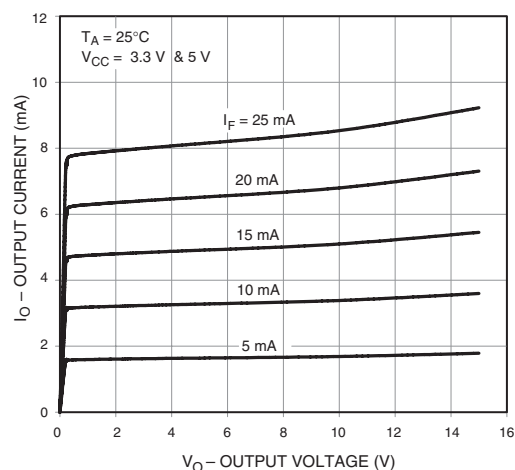


Figure 6. Output Current vs. Output Voltage

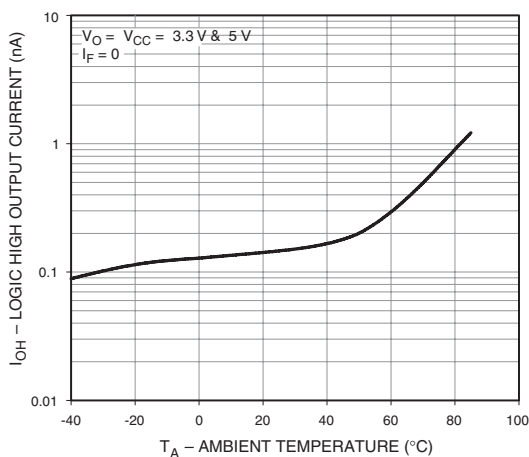


Figure 7. Logic High Output Current vs. Ambient Temperature

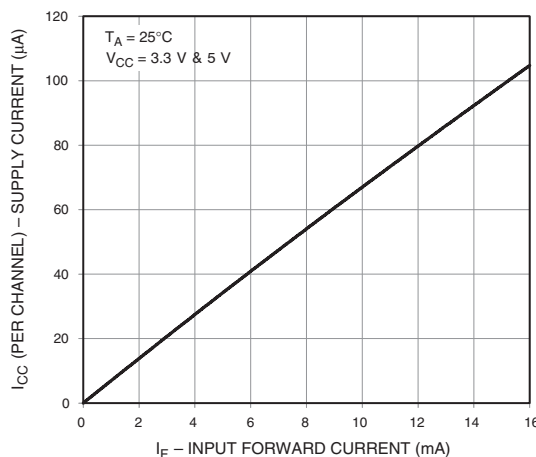


Figure 8. Supply Current vs. Input Forward Current

Typical Performance Curves (Continued)

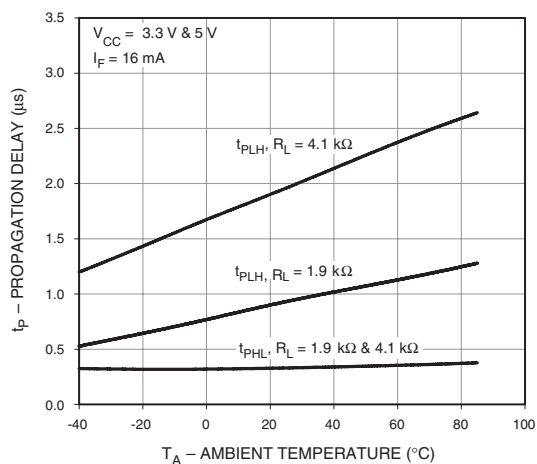


Figure 9. Propagation Delay vs. Ambient Temperature

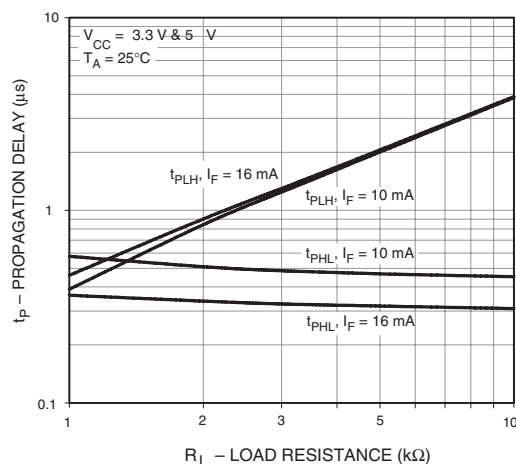


Figure 10. Propagation Delay vs. Load Resistance

Test Circuits

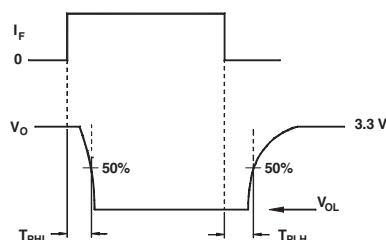
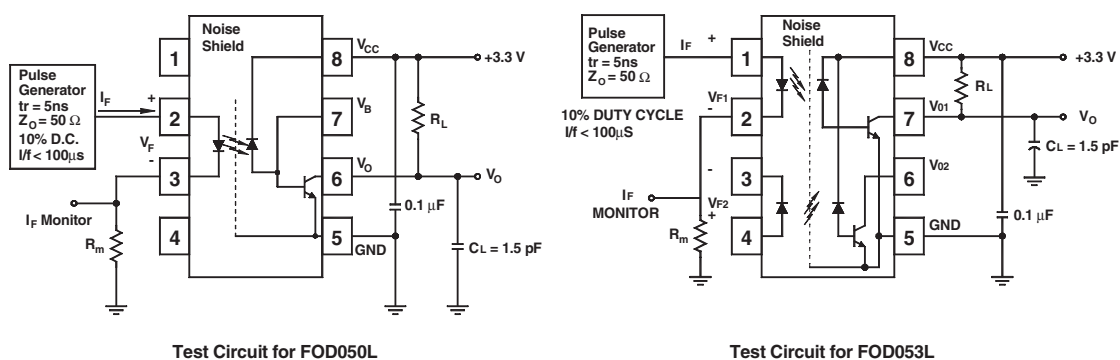


Figure 11. Switching Time Test Circuit

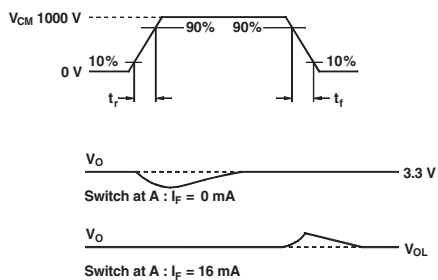
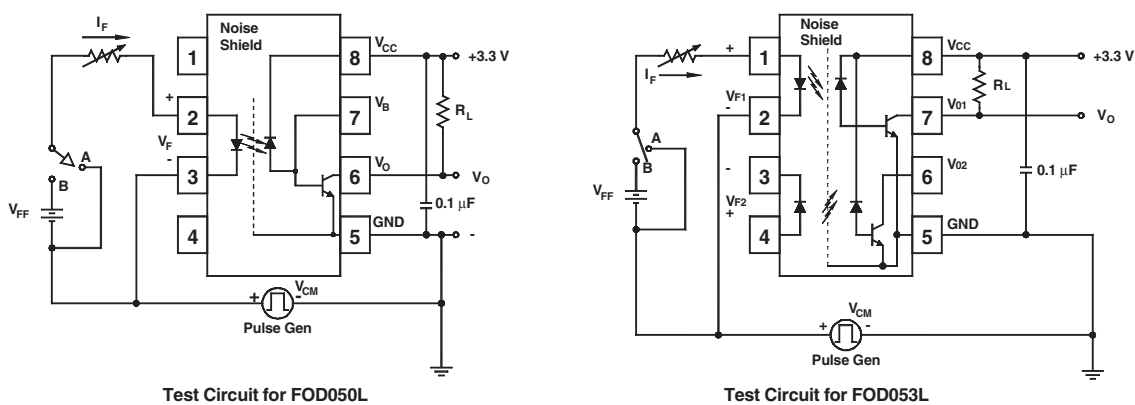


Figure 12. Common Mode Immunity Test Circuit

Reflow Profile

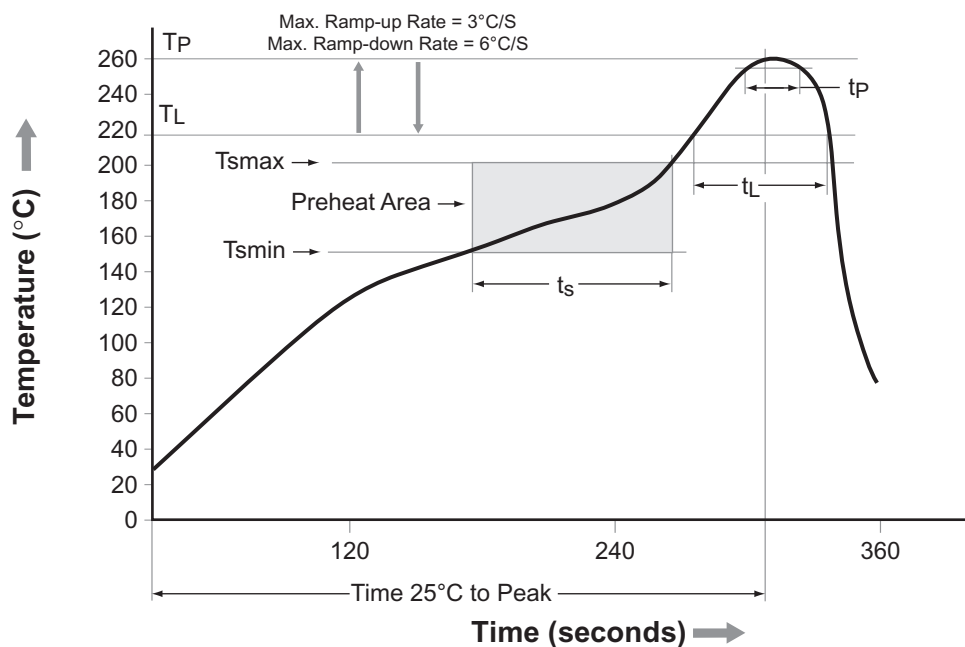


Figure 13. Reflow Profile

Profile Feature	Pb-Free Assembly Profile
Temperature Minimum (Tsm)	150°C
Temperature Maximum (Tsp)	260°C
Time (ts) from (Tsm to Tsp)	60–120 seconds
Ramp-up Rate (Tl to Tsp)	3°C/second maximum
Liquidous Temperature (Tl)	217°C
Time (tl) Maintained Above (Tl)	60–150 seconds
Peak Body Package Temperature	260°C +0°C / –5°C
Time (tp) within 5°C of 260°C	30 seconds
Ramp-down Rate (Tp to Tl)	6°C/second maximum
Time 25°C to Peak Temperature	8 minutes maximum

Ordering Information

Part Number	Package	Packing Method
FOD050L	Small Outline 8-Pin	Tube (100 Units)
FOD050LR2	Small Outline 8-Pin	Tape and Reel (1000 Units)
FOD050LV	Small Outline 8-Pin, DIN EN/IEC60747-5-5 Option	Tube (100 Units)
FOD050LR2V	Small Outline 8-Pin, DIN EN/IEC60747-5-5 Option	Tape and Reel (1000 Units)

Note:

7. The product orderable part number system listed in this table also applies to the FOD053L product.

Marking Information

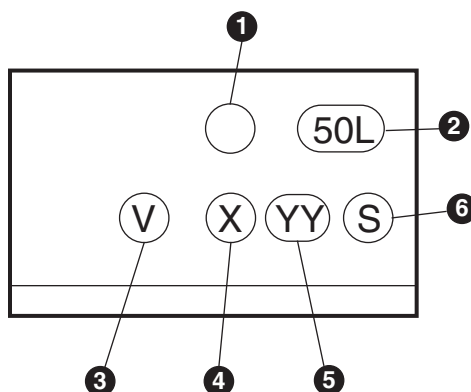
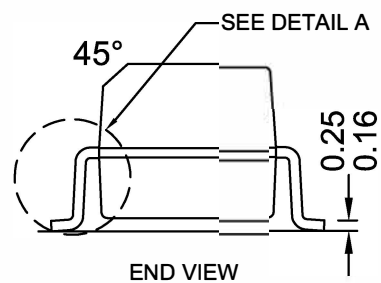
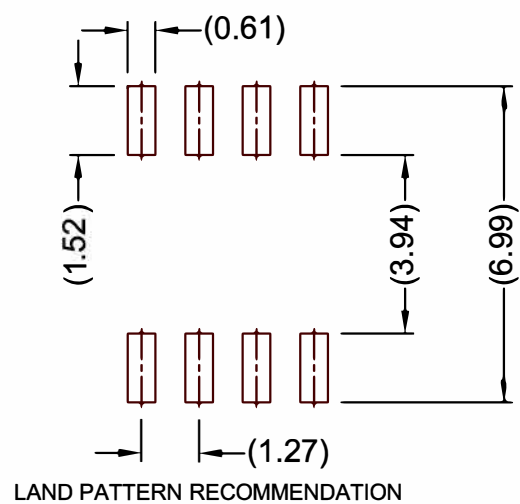


Figure 14. Top Mark

Table 1. Top Mark Definitions

1	ON Semiconductor Logo
2	Device Number
3	DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option)
4	One-Digit Year Code, e.g., "5"
5	Digit Work Week, Ranging from "01" to "53"
6	Assembly Package Code



A) NO STANDARD APPLIES TO THIS PACKAGE
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DIMENSIONS DO NOT INCLUDE MOLD
FLASH OR BURRS.
D) LANDPATTERN STANDARD: SOIC127P600X175-8M.
E) DRAWING FILENAME: MKT-M08Erev5

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910

ON Semiconductor Website: www.onsemi.com

Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local
Sales Representative